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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	F ² MC-8FX
Core Size	8-Bit
Speed	16MHz
Connectivity	I ² C, LINbus, SIO, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	29
Program Memory Size	20KB (20K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1008 x 8
Voltage - Supply (Vcc/Vdd)	2.4V ~ 5.5V
Data Converters	A/D 8x8/10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb95f334kpmc-g-sne2

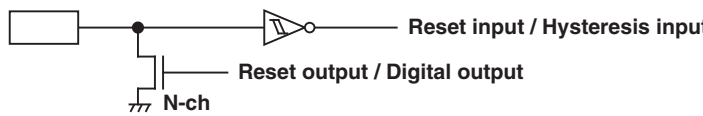
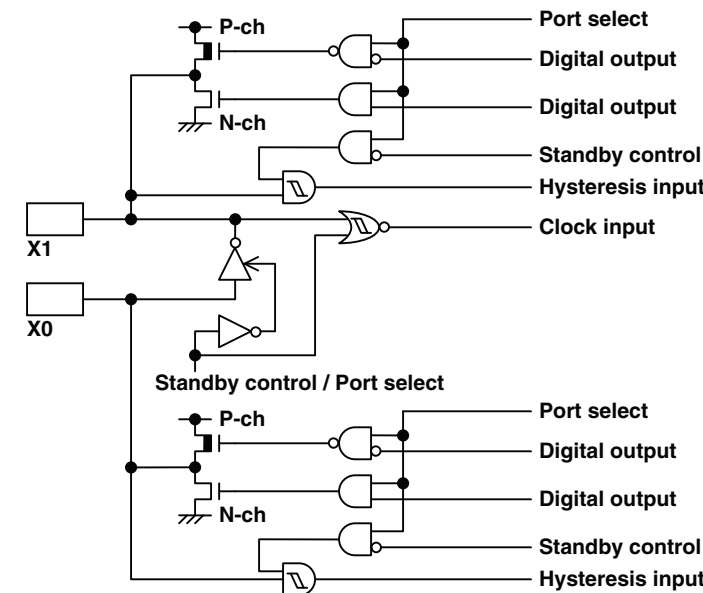
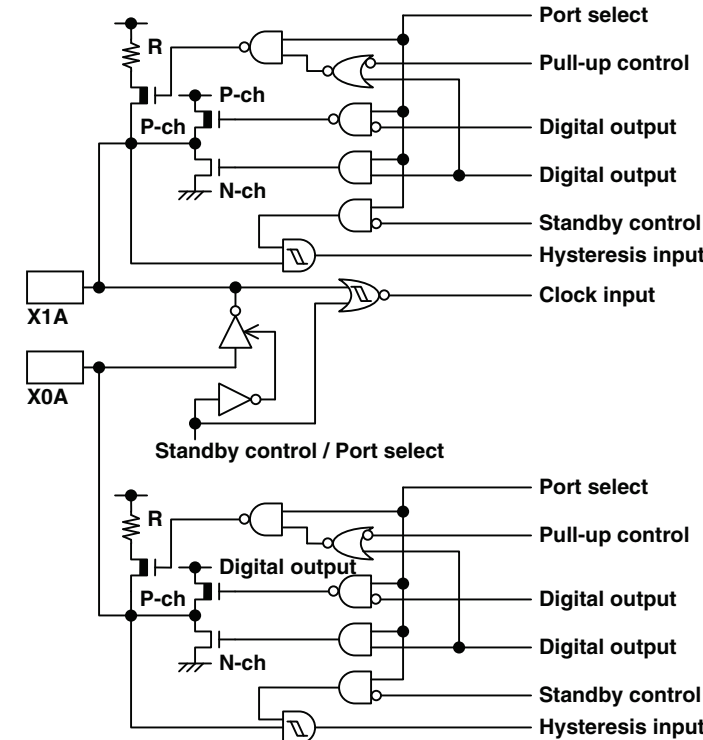
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Part number	MB95F332H	MB95F333H	MB95F334H	MB95F332K	MB95F333K	MB95F334K
Parameter						
UART/SIO	1 channel Data transfer with UART/SIO is enabled. It has a full duplex double buffer, variable data length (5/6/7/8 bits), a built-in baud rate generator and an error detection function. It uses the NRZ type transfer format. LSB-first data transfer and MSB-first data transfer are available to use. Clock-asynchronous (UART) serial data transfer and clock-synchronous (SIO) serial data transfer is enabled.					
I ² C	1 channel Master/slave transmission and receiving It has a bus error function, an arbitration function, a transmission direction detection function and a wake-up function. It also has functions of generating and detecting repeated START conditions.					
8/16-bit PPG	3 channels Each channel of PPG can be used as two 8-bit PPG channels or a single 16-bit PPG channel. The counter operating clock can be selected from eight clock sources.					
16-bit PPG	PWM mode and one-shot mode are available to use. The counter operating clock can be selected from eight clock sources. It supports external trigger start. It can work independently or together with the multi-pulse generator.					
16-bit reload timer	Two clock modes and two counter operating modes are available to use. It can output square waveform. Count clock: it can be selected from internal clocks (seven types) and external clocks. Two counter operating modes: reload mode and one-shot mode It can work independently or together with the multi-pulse generator.					
Multi-pulse generator (for DC motor control)	16-bit PPG timer: 1 channel 16-bit reload timer operations: toggle output, one-shot output Event counter: 1 channel Waveform sequencer (including a 16-bit timer equipped with a buffer and a compare clear function)					
Watch prescaler	Eight different time intervals can be selected.					
Flash memory	It supports automatic programming, Embedded Algorithm, and write/erase/erase-suspend/erase-resume commands. It has a flag indicating the completion of the operation of Embedded Algorithm. Number of write/erase cycles: 100000 Data retention time: 20 years Flash security feature for protecting the content of the Flash memory					
Standby mode	Sleep mode, stop mode, watch mode, time-base timer mode					
Package	FPT-32P-M30 DIP-32P-M06 LCC-32P-M19					

Pin no.		Pin name	I/O circuit type*4	Function
LQFP32*1 & QFN32*2	SH-DIP32*3			
10	14	P62	D	General-purpose I/O port High-current pin
		TO10		8/16-bit composite timer ch. 1 output pin
		PPG00		8/16-bit PPG ch. 0 output pin
		OPT0		MPG waveform sequencer output pin
11	15	P61	I	General-purpose I/O port
		INT09		External interrupt input pin
		SCL		I ² C clock I/O pin
		TI1		16-bit reload timer ch. 1 input pin
12	16	P60	I	General-purpose I/O port
		INT08		External interrupt input pin
		SDA		I ² C data I/O pin
		DTTI		MPG waveform sequencer input pin
13	17	P00	E	General-purpose I/O port
		INT00		External interrupt input pin
		AN00		A/D converter analog input pin
14	18	P01	E	General-purpose I/O port
		INT01		External interrupt input pin
		AN01		A/D converter analog input pin
15	19	P02	E	General-purpose I/O port
		INT02		External interrupt input pin
		AN02		A/D converter analog input pin
		SCK		LIN-UART clock I/O pin
16	20	P03	E	General-purpose I/O port
		INT03		External interrupt input pin
		AN03		A/D converter analog input pin
		SOT		LIN-UART data output pin
17	21	P04	F	General-purpose I/O port
		INT04		External interrupt input pin
		AN04		A/D converter analog input pin
		SIN		LIN-UART data input pin
		HCLK1		External clock input pin
		EC0		8/16-bit composite timer ch. 0 clock input pin

(Continued)

6. I/O Circuit Type

Type	Circuit	Remarks
A		<ul style="list-style-type: none"> ■ N-ch open drain output ■ Hysteresis input ■ Reset output
B		<ul style="list-style-type: none"> ■ Oscillation circuit ■ High-speed side Feedback resistance: approx. 1 MΩ ■ CMOS output ■ Hysteresis input
C		<ul style="list-style-type: none"> ■ Oscillation circuit ■ Low-speed side Feedback resistance: approx. 10 MΩ ■ CMOS output ■ Hysteresis input ■ Pull-up control available

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Address	Register abbreviation	Register name	R/W	Initial value
0F92 _H	T01CR0	8/16-bit composite timer 01 status control register 0 ch. 0	R/W	00000000 _B
0F93 _H	T00CR0	8/16-bit composite timer 00 status control register 0 ch. 0	R/W	00000000 _B
0F94 _H	T01DR	8/16-bit composite timer 01 data register ch. 0	R/W	00000000 _B
0F95 _H	T00DR	8/16-bit composite timer 00 data register ch. 0	R/W	00000000 _B
0F96 _H	TMCR0	8/16-bit composite timer 00/01 timer mode control register ch. 0	R/W	00000000 _B
0F97 _H	T11CR0	8/16-bit composite timer 11 status control register 0 ch. 1	R/W	00000000 _B
0F98 _H	T10CR0	8/16-bit composite timer 10 status control register 0 ch. 1	R/W	00000000 _B
0F99 _H	T11DR	8/16-bit composite timer 11 data register ch. 1	R/W	00000000 _B
0F9A _H	T10DR	8/16-bit composite timer 10 data register ch. 1	R/W	00000000 _B
0F9B _H	TMCR1	8/16-bit composite timer 10/11 timer mode control register ch. 1	R/W	00000000 _B
0F9C _H	PPS01	8/16-bit PPG01 cycle setting buffer register ch. 0	R/W	11111111 _B
0F9D _H	PPS00	8/16-bit PPG00 cycle setting buffer register ch. 0	R/W	11111111 _B
0F9E _H	PDS01	8/16-bit PPG01 duty setting buffer register ch. 0	R/W	11111111 _B
0F9F _H	PDS00	8/16-bit PPG00 duty setting buffer register ch. 0	R/W	11111111 _B
0FA0 _H	PPS11	8/16-bit PPG11 cycle setting buffer register ch. 1	R/W	11111111 _B
0FA1 _H	PPS10	8/16-bit PPG10 cycle setting buffer register ch. 1	R/W	11111111 _B
0FA2 _H	PDS11	8/16-bit PPG11 duty setting buffer register ch. 1	R/W	11111111 _B
0FA3 _H	PDS10	8/16-bit PPG10 duty setting buffer register ch. 1	R/W	11111111 _B
0FA4 _H	PPGS	8/16-bit PPG startup register	R/W	00000000 _B
0FA5 _H	REVC	8/16-bit PPG output reverse register	R/W	00000000 _B
0FA6 _H	PPS21	8/16-bit PPG21 cycle setting buffer register ch. 2	R/W	11111111 _B
0FA7 _H	PPS20	8/16-bit PPG20 cycle setting buffer register ch. 2	R/W	11111111 _B
0FA8 _H	TMRH1	16-bit timer register (upper) ch. 1	R/W	00000000 _B
	TMRLRH1	16-bit reload register (upper) ch. 1		
0FA9 _H	TMRL1	16-bit timer register (lower) ch. 1	R/W	00000000 _B
	TMRLRL1	16-bit reload register (lower) ch. 1		
0FAA _H	PDS21	8/16-bit PPG21 duty setting buffer register ch. 2	R/W	11111111 _B
0FAB _H	PDS20	8/16-bit PPG20 duty setting buffer register ch. 2	R/W	11111111 _B
0FAC _H to 0FAF _H	—	(Disabled)	—	—
0FB0 _H	PDCRH1	16-bit PPG down counter register (upper) ch. 1	R	00000000 _B
0FB1 _H	PDCRL1	16-bit PPG down counter register (lower) ch. 1	R	00000000 _B
0FB2 _H	PCSRH1	16-bit PPG cycle setting buffer register (upper) ch. 1	R/W	11111111 _B
0FB3 _H	PCSRL1	16-bit PPG cycle setting buffer register (lower) ch. 1	R/W	11111111 _B
0FB4 _H	PDUTH1	16-bit PPG duty setting buffer register (upper) ch. 1	R/W	11111111 _B
0FB5 _H	PDUTL1	16-bit PPG duty setting buffer register (lower) ch. 1	R/W	11111111 _B

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13. Electrical Characteristics

13.1 Absolute Maximum Ratings

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Power supply voltage*1	V_{CC}	$V_{SS} - 0.3$	$V_{SS} + 6$	V	
Input voltage*1	V_I	$V_{SS} - 0.3$	$V_{SS} + 6$	V	*2
Output voltage*1	V_O	$V_{SS} - 0.3$	$V_{SS} + 6$	V	*2
Maximum clamp current	I_{CLAMP}	-2	+2	mA	Applicable to specific pins*3
Total maximum clamp current	$\sum I_{CLAMP} $	—	20	mA	Applicable to specific pins*3
"L" level maximum output current	I_{OL1}	—	15	mA	Other than P62 to P67
	I_{OL2}	—	15		P62 to P67
"L" level average current	I_{OLAV1}	—	4	mA	Other than P62 to P67 Average output current = operating current × operating ratio (1 pin)
	I_{OLAV2}	—	12		P62 to P67 Average output current = operating current × operating ratio (1 pin)
"L" level total maximum output current	$\sum I_{OL}$	—	100	mA	
"L" level total average output current	$\sum I_{OLAV}$	—	50	mA	Total average output current = operating current × operating ratio (Total number of pins)
"H" level maximum output current	I_{OH1}	—	-15	mA	Other than P62 to P67
	I_{OH2}	—	-15		P62 to P67
"H" level average current	I_{OHAV1}	—	-4	mA	Other than P62 to P67 Average output current = operating current × operating ratio (1 pin)
	I_{OHAV2}	—	-8		P62 to P67 Average output current = operating current × operating ratio (1 pin)
"H" level total maximum output current	$\sum I_{OH}$	—	-100	mA	
"H" level total average output current	$\sum I_{OHAV}$	—	-50	mA	Total average output current = operating current × operating ratio (Total number of pins)
Power consumption	P_d	—	320	mW	
Operating temperature	T_A	-40	+85	°C	
Storage temperature	T_{stg}	-55	+150	°C	

(Continued)

$(V_{CC} = 5.0 V \pm 10\%, V_{SS} = 0.0 V, T_A = -40^\circ C \text{ to } +85^\circ C)$

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current*2	I _{CC}	V _{CC} (External clock operation)	V _{CC} = 5.5 V F _{CH} = 32 MHz F _{MP} = 16 MHz Main clock mode (divided by 2)	—	13	17	mA	Flash memory product (except writing and erasing)
			—	20.5	26.5	mA		Flash memory product (at writing and erasing)
			—	15	21		mA	At A/D conversion
	I _{CCS}		V _{CC} = 5.5 V F _{CH} = 32 MHz F _{MP} = 16 MHz Main sleep mode (divided by 2)	—	5.5	9		mA
	I _{CCL}		V _{CC} = 5.5 V F _{CL} = 32 kHz F _{MPL} = 16 kHz Subclock mode (divided by 2) T _A = +25°C	—	65	153	μA	
	I _{CCLS}		V _{CC} = 5.5 V F _{CL} = 32 kHz F _{MPL} = 16 kHz Subsleep mode (divided by 2) T _A = +25°C	—	10	84		μA
	I _{CCT}		V _{CC} = 5.5 V F _{CL} = 32 kHz Watch mode Main stop mode T _A = +25°C	—	5	30	μA	
	I _{CCMCR}		V _{CC}	V _{CC} = 5.5 V F _{CRH} = 12.5 MHz F _{MP} = 12.5 MHz Main CR clock mode	—	10		13.2
I _{CCSCR}	V _{CC} = 5.5 V Sub-CR clock mode (divided by 2) T _A = +25°C	—		110	410	μA		

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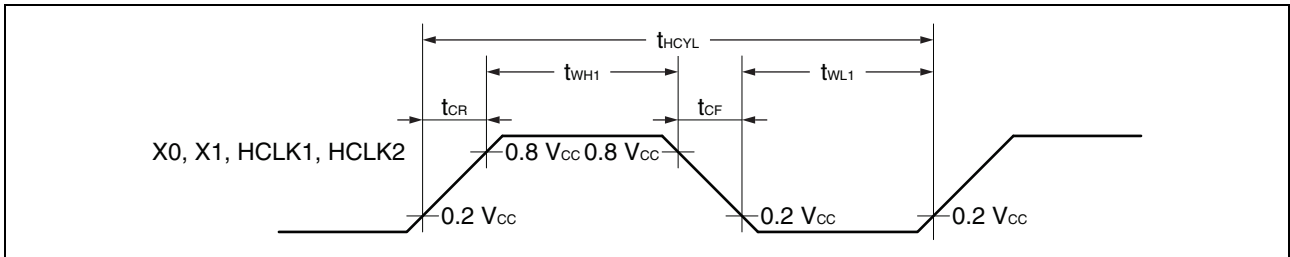
 ($V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current*2	I_{CCTS}	V_{CC} (External clock operation)	$V_{CC} = 5.5\text{ V}$ $F_{CH} = 32\text{ MHz}$ Time-base timer mode $T_A = +25^\circ\text{C}$	—	1.1	3	mA	
	I_{CCH}		$V_{CC} = 5.5\text{ V}$ Substop mode $T_A = +25^\circ\text{C}$	—	3.5	22.5	μA	
	I_{LVD}	V_{CC}	Current consumption for low-voltage detection circuit only	—	37	54	μA	
	I_{CRH}		Current consumption for the main CR oscillator	—	0.5	0.6	mA	
	I_{CRL}		Current consumption for the sub-CR oscillator oscillating at 100 kHz	—	20	72	μA	

*1: The input levels of P04, P16, P60 and P61 can be switched between "CMOS input level" and "hysteresis input level". The input level selection register (ILSR) is used to switch between the two input levels.

*2: • The power supply current is determined by the external clock. When the low-voltage detection option is selected, the power-supply current will be the sum of adding the current consumption of the low-voltage detection circuit (I_{LVD}) to one of the value from I_{CC} to I_{CCH} . In addition, when both the low-voltage detection option and the CR oscillator are selected, the power supply current will be the sum of adding up the current consumption of the low-voltage detection circuit, the current consumption of the CR oscillators (I_{CRH} , I_{CRL}) and a specified value. In on-chip debug mode, the CR oscillator (I_{CRH}) and the low-voltage detection circuit are always enabled, and current consumption therefore increases accordingly.

- See "4. AC Characteristics: (1) Clock Timing" for F_{CH} and F_{CL} .
- See "4. AC Characteristics: (2) Source Clock/Machine Clock" for F_{MP} and F_{MPL} .



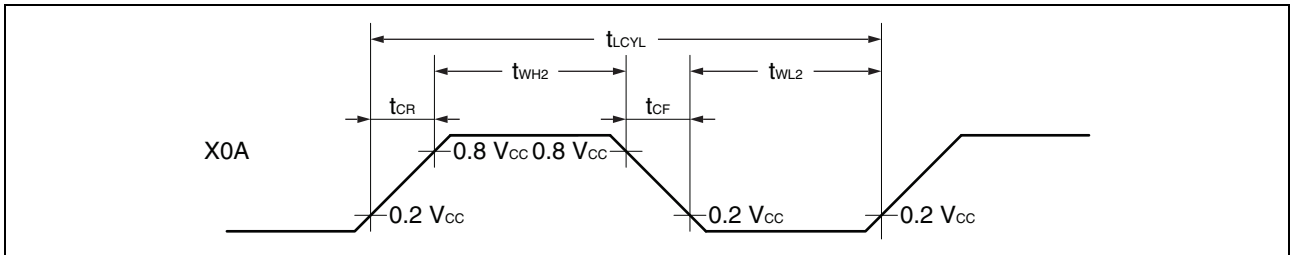
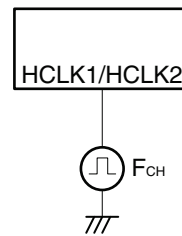
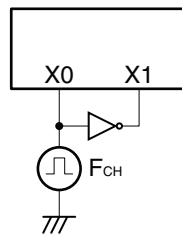
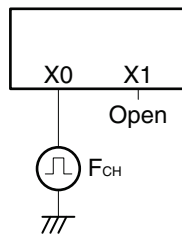
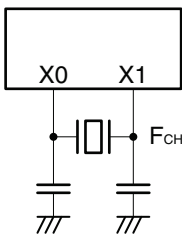
• Figure of main clock input port external connection

When a crystal oscillator or a ceramic oscillator is used

When the external clock is used (X1 is open)

When the external clock is used

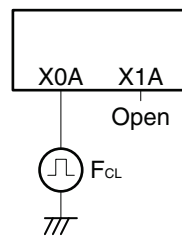
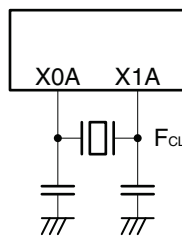
When the external clock is used



• Figure of subclock input port external connection

When a crystal oscillator or a ceramic oscillator is used

When the external clock is used



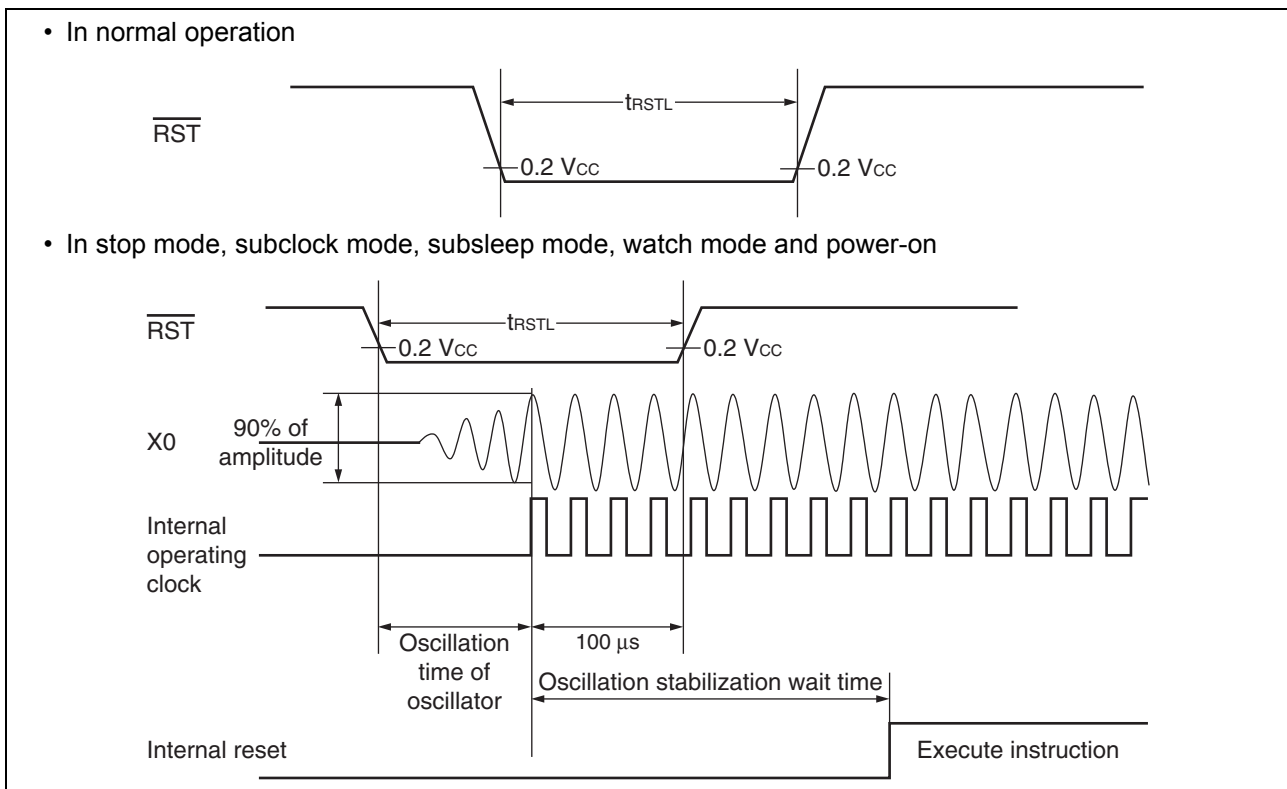
13.4.3 External Reset

($V_{CC} = 5.0\text{ V} \pm 10\%$, $V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Value		Unit	Remarks
		Min	Max		
$\overline{\text{RST}}$ "L" level pulse width	t_{RSTL}	$2 t_{\text{MCLK}}^{*1}$	—	ns	In normal operation
		Oscillation time of the oscillator ^{*2} + 100	—	μs	In stop mode, subclock mode, subsleep mode, watch mode, and power-on
		100	—	μs	In time-base timer mode

*1: See "(2) Source Clock/Machine Clock" for t_{MCLK} .

*2: The oscillation time of an oscillator is the time for it to reach 90% of its amplitude. The crystal oscillator has an oscillation time of between several ms and tens of ms. The ceramic oscillator has an oscillation time of between hundreds of μs and several ms. The external clock has an oscillation time of 0 ms. The CR oscillator clock has an oscillation time of between several μs and several ms.



13.4.4 Power-on Reset

($V_{SS} = 0.0\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min	Max		
Power supply rising time	t_R	—	—	50	ms	
Power supply cutoff time	t_{OFF}	—	1	—	ms	Wait time until power-on

13.4.6 LIN-UART Timing

Sampling is executed at the rising edge of the sampling clock*¹, and serial clock delay is disabled*².
 (ESCR register: SCES bit = 0, ECCR register: SCDE bit = 0)

($V_{CC} = 5.0 V \pm 10\%$, $AV_{SS} = V_{SS} = 0.0 V$, $T_A = -40^\circ C$ to $+85^\circ C$)

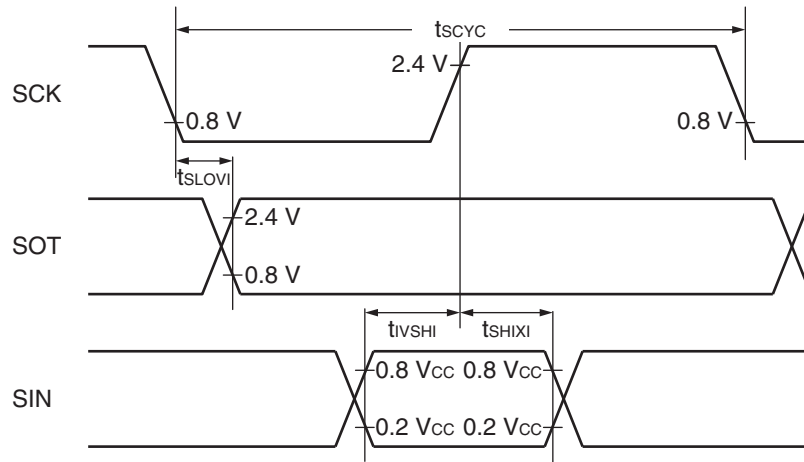
Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t_{SCYC}	SCK	Internal clock operation output pin: $C_L = 80 \text{ pF} + 1 \text{ TTL}$	$5 t_{MCLK}^{*3}$	—	ns
SCK $\downarrow \rightarrow$ SOT delay time	t_{SLOVI}	SCK, SOT		-95	+95	ns
Valid SIN \rightarrow SCK \uparrow	t_{IVSHI}	SCK, SIN		$t_{MCLK}^{*3} + 190$	—	ns
SCK $\uparrow \rightarrow$ valid SIN hold time	t_{SHIXI}	SCK, SIN		0	—	ns
Serial clock "L" pulse width	t_{SLSH}	SCK	External clock operation output pin: $C_L = 80 \text{ pF} + 1 \text{ TTL}$	$3 t_{MCLK}^{*3} - t_R$	—	ns
Serial clock "H" pulse width	t_{SHSL}	SCK		$t_{MCLK}^{*3} + 95$	—	ns
SCK $\downarrow \rightarrow$ SOT delay time	t_{SLOVE}	SCK, SOT		—	$2 t_{MCLK}^{*3} + 95$	ns
Valid SIN \rightarrow SCK \uparrow	t_{IVSHE}	SCK, SIN		190	—	ns
SCK $\uparrow \rightarrow$ valid SIN hold time	t_{SHIXE}	SCK, SIN		$t_{MCLK}^{*3} + 95$	—	ns
SCK fall time	t_F	SCK		—	10	ns
SCK rise time	t_R	SCK		—	10	ns

*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

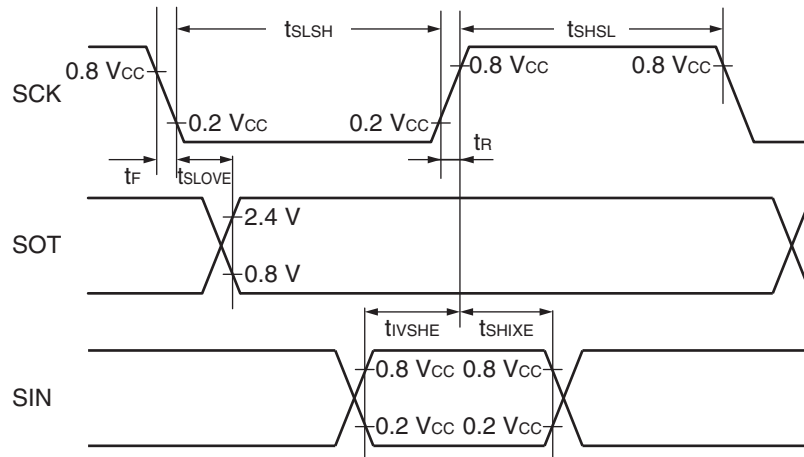
*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

*3: See "(2) Source Clock/Machine Clock" for t_{MCLK} .

• Internal shift clock mode



• External shift clock mode



Sampling is executed at the falling edge of the sampling clock*¹, and serial clock delay is disabled*².
 (ESCR register: SCES bit = 1, ECCR register: SCDE bit = 0)

(V_{CC} = 5.0 V±10%, V_{SS} = 0.0 V, T_A = -40°C to +85°C)

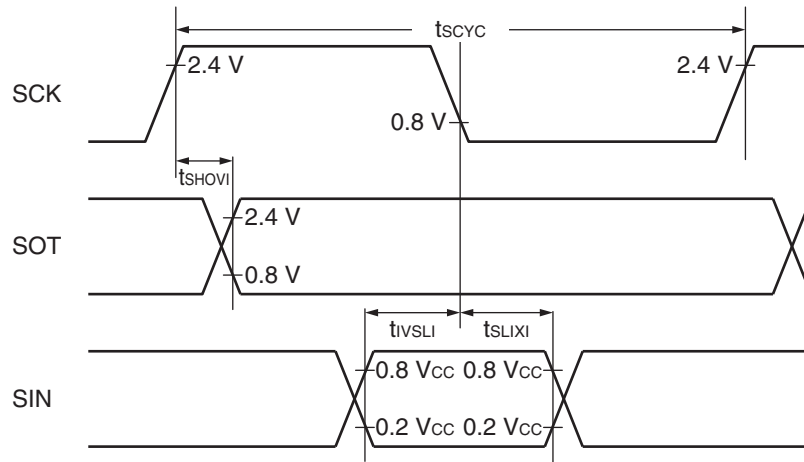
Parameter	Symbol	Pin name	Condition	Value		Unit
				Min	Max	
Serial clock cycle time	t _{SCYC}	SCK	Internal clock operation output pin: C _L = 80 pF + 1 TTL	5 t _{MCLK} * ³	—	ns
SCK ↑ → SOT delay time	t _{SHOVI}	SCK, SOT		-95	+95	ns
Valid SIN → SCK ↓	t _{IVSLI}	SCK, SIN		t _{MCLK} * ³ + 190	—	ns
SCK ↓ → valid SIN hold time	t _{SLIXI}	SCK, SIN		0	—	ns
Serial clock "H" pulse width	t _{SHSL}	SCK	External clock operation output pin: C _L = 80 pF + 1 TTL	3 t _{MCLK} * ³ - t _R	—	ns
Serial clock "L" pulse width	t _{SLSH}	SCK		t _{MCLK} * ³ + 95	—	ns
SCK ↑ → SOT delay time	t _{SHOVE}	SCK, SOT		—	2 t _{MCLK} * ³ + 95	ns
Valid SIN → SCK ↓	t _{IVSLE}	SCK, SIN		190	—	ns
SCK ↓ → valid SIN hold time	t _{SLIXE}	SCK, SIN		t _{MCLK} * ³ + 95	—	ns
SCK fall time	t _F	SCK		—	10	ns
SCK rise time	t _R	SCK		—	10	ns

*1: There is a function used to choose whether the sampling of reception data is performed at a rising edge or a falling edge of the serial clock.

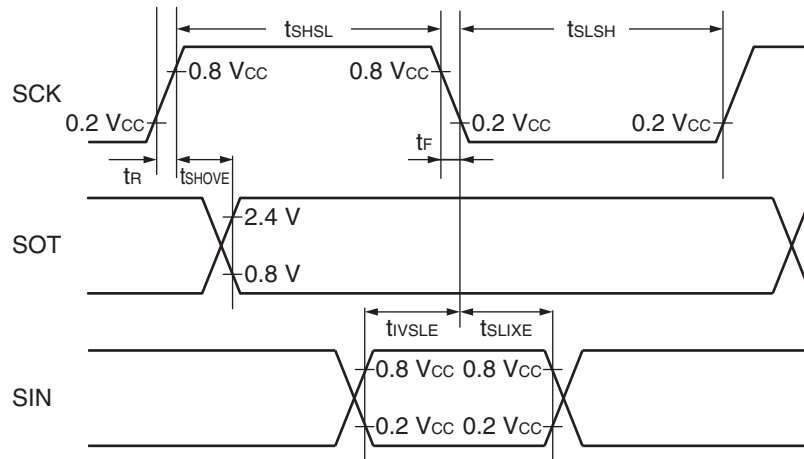
*2: The serial clock delay function is a function used to delay the output signal of the serial clock for half the clock.

*3: See "(2) Source Clock/Machine Clock" for t_{MCLK}.

• Internal shift clock mode



• External shift clock mode



13.4.8 I²C Timing

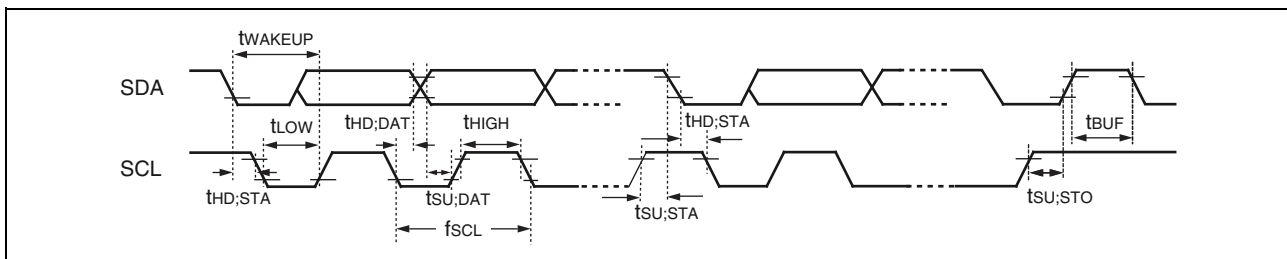
(V_{CC} = 5.0 V±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value				Unit
				Standard-mode		Fast-mode		
				Min	Max	Min	Max	
SCL clock frequency	f _{SCL}	SCL	R = 1.7 kΩ, C = 50 pF ^{*1}	0	100	0	400	kHz
(Repeated) START condition hold time SDA ↓ → SCL ↓	t _{HD;STA}	SCL, SDA		4.0	—	0.6	—	μs
SCL clock "L" width	t _{LOW}	SCL		4.7	—	1.3	—	μs
SCL clock "H" width	t _{HIGH}	SCL		4.0	—	0.6	—	μs
(Repeated) START condition hold time SCL ↑ → SDA ↓	t _{SU;STA}	SCL, SDA		4.7	—	0.6	—	μs
Data hold time SCL ↓ → SDA ↓↑	t _{HD;DAT}	SCL, SDA		0	3.45 ^{*2}	0	0.9 ^{*3}	μs
Data setup time SDA ↓↑ → SCL ↑	t _{SU;DAT}	SCL, SDA		0.25	—	0.1	—	μs
STOP condition setup time SCL ↑ → SDA ↑	t _{SU;STO}	SCL, SDA		4	—	0.6	—	μs
Bus free time between STOP condition and START condition	t _{BUF}	SCL, SDA		4.7	—	1.3	—	μs

*1: R represents the pull-up resistor of the SCL and SDA lines, and C the load capacitor of the SCL and SDA lines.

*2: The maximum t_{HD;DAT} in the Standard-mode is applicable only when the time during which the device is holding the SCL signal at "L" (t_{LOW}) does not extend.

*3: A Fast-mode I²C-bus device can be used in a Standard-mode I²C-bus system, provided that the condition of t_{SU;DAT} ≥ 250 ns is fulfilled.

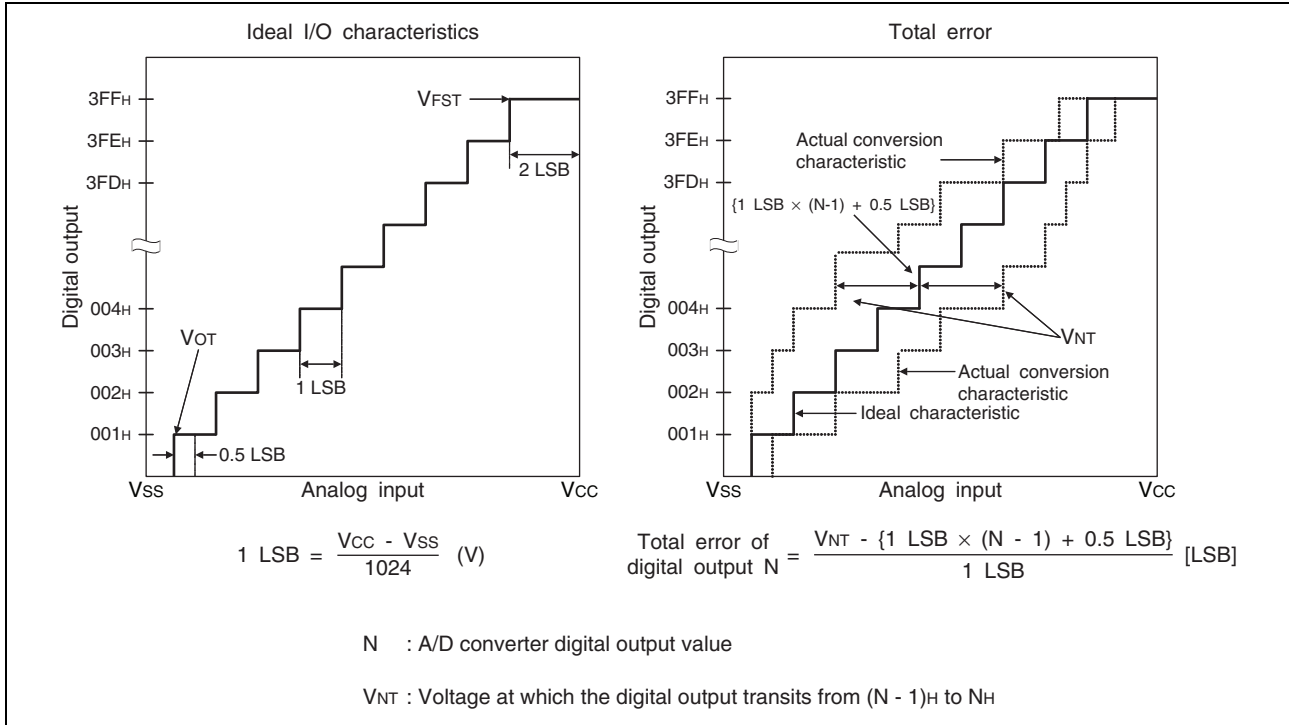


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$(V_{CC} = 5.0 V \pm 10\%, AV_{SS} = V_{SS} = 0.0 V, T_A = -40^\circ C \text{ to } +85^\circ C)$

Parameter	Symbol	Pin name	Condition	Value*2		Unit	Remarks
				Min	Max		
SCL clock "L" width	t_{LOW}	SCL	R = 1.7 k Ω , C = 50 pF*1	$(2 + nm/2)t_{MCLK} - 20$	—	ns	Master mode
SCL clock "H" width	t_{HIGH}	SCL		$(nm/2)t_{MCLK} - 20$	$(nm/2)t_{MCLK} + 20$	ns	Master mode
START condition hold time	$t_{HD;STA}$	SCL, SDA		$(-1 + nm/2)t_{MCLK} - 20$	$(-1 + nm)t_{MCLK} + 20$	ns	Master mode Maximum value is applied when m, n = 1, 8. Otherwise, the minimum value is applied.
STOP condition setup time	$t_{SU;STO}$	SCL, SDA		$(1 + nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Master mode
START condition setup time	$t_{SU;STA}$	SCL, SDA		$(1 + nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Master mode
Bus free time between STOP condition and START condition	t_{BUF}	SCL, SDA		$(2 nm + 4)t_{MCLK} - 20$	—	ns	
Data hold time	$t_{HD;DAT}$	SCL, SDA		$3 t_{MCLK} - 20$	—	ns	Master mode
Data setup time	$t_{SU;DAT}$	SCL, SDA		$(-2 + nm/2)t_{MCLK} - 20$	$(-1 + nm/2)t_{MCLK} + 20$	ns	Master mode When assuming that "L" of SCL is not extended, the minimum value is applied to first bit of continuous data. Otherwise, the maximum value is applied.
Setup time between clearing interrupt and SCL rising	$t_{SU;INT}$	SCL		$(nm/2)t_{MCLK} - 20$	$(1 + nm/2)t_{MCLK} + 20$	ns	Minimum value is applied to interrupt at 9th SCL \downarrow . Maximum value is applied to the interrupt at the 8th SCL \downarrow .

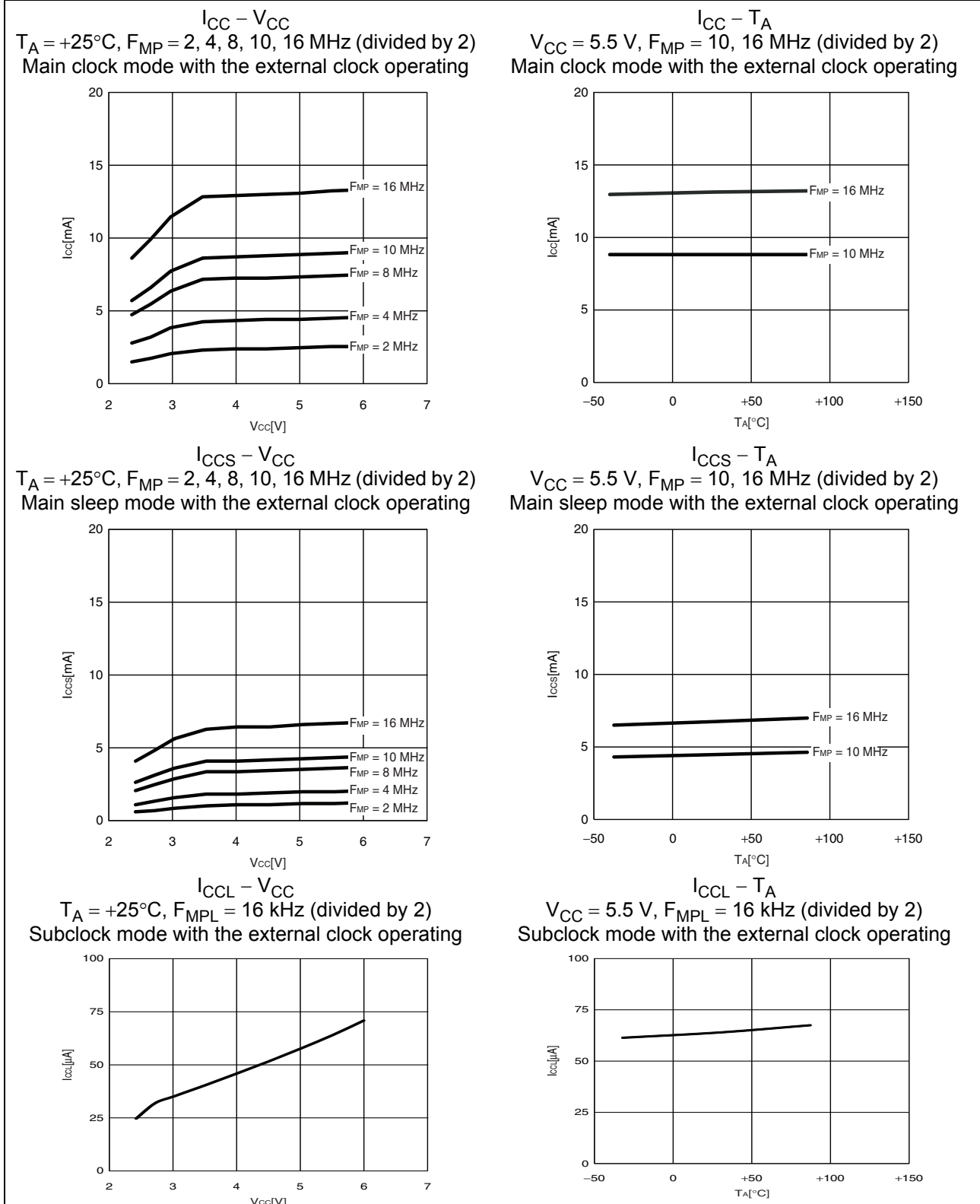
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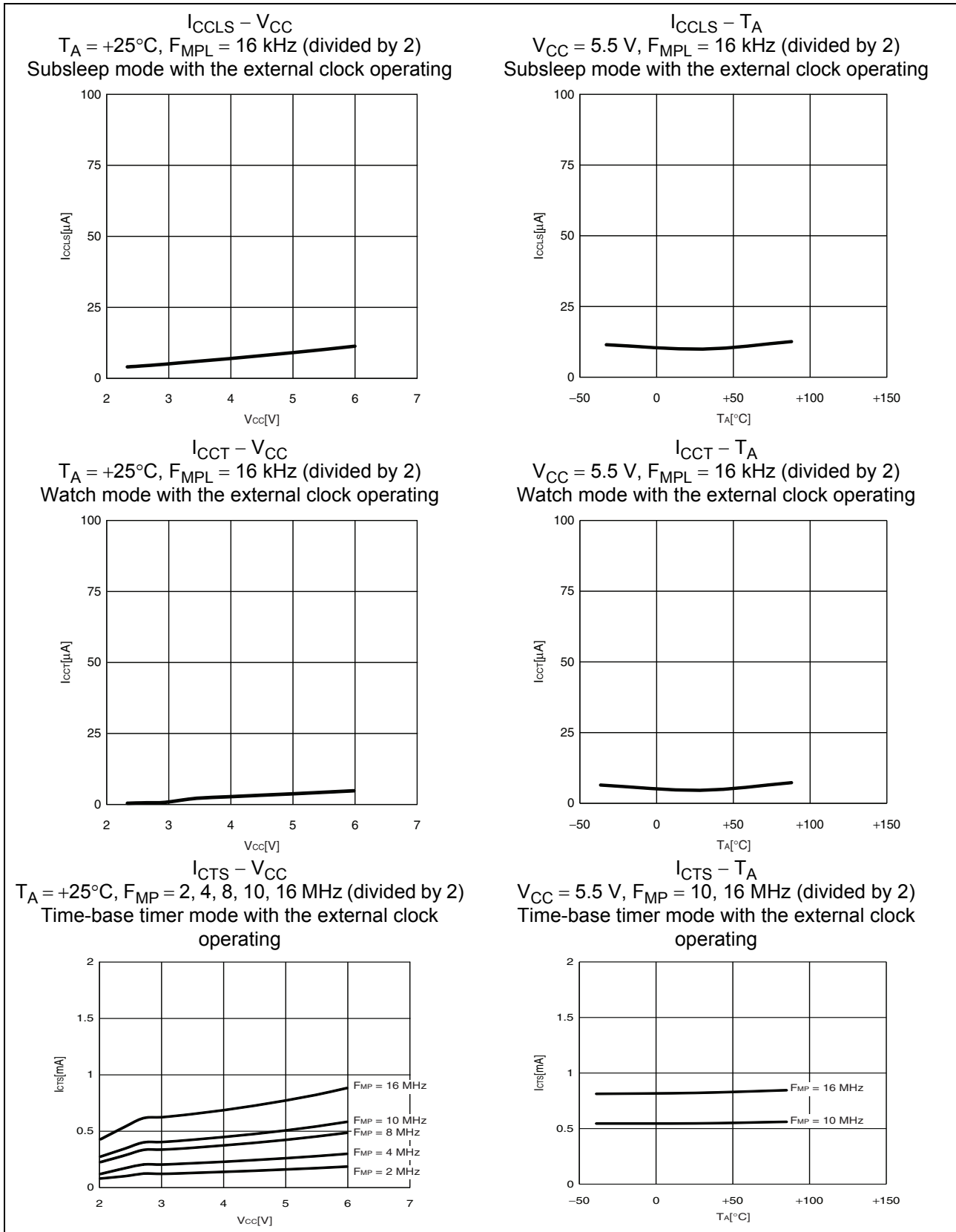


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14. Sample Characteristics

■ Power supply current temperature characteristics





16. Ordering Information

Part Number	Package
MB95F332HPMC-G-SNE2 MB95F332KPMC-G-SNE2 MB95F333HPMC-G-SNE2 MB95F333KPMC-G-SNE2 MB95F334HPMC-G-SNE2 MB95F334KPMC-G-SNE2	32-pin plastic LQFP (FPT-32P-M30)
MB95F332HP-G-SH-SNE2 MB95F332KP-G-SH-SNE2 MB95F333HP-G-SH-SNE2 MB95F333KP-G-SH-SNE2 MB95F334HP-G-SH-SNE2 MB95F334KP-G-SH-SNE2	32-pin plastic SH-DIP (DIP-32P-M06)
MB95F332HWQN-G-SNE1 MB95F332KWQN-G-SNE1 MB95F333HWQN-G-SNE1 MB95F333KWQN-G-SNE1 MB95F334HWQN-G-SNE1 MB95F334KWQN-G-SNE1	32-pin plastic QFN (LCC-32P-M19)

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Document Number: 002-07522				
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